

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S65 3	7	sram and driver adj transistor and access adj transistor and bit adj lines and ((mono-domain or crystalline or recrystallize) adj region) and source and drain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/12 14:57
S65 4	1	("5514880").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	OFF	2005/04/12 15:06
S65 5	0	((crystalline or crystallize) near semiconductor adj film) with drain and source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/12 15:08
S65 6	0	((crystalline or crystallize) near semiconductor adj film) same drain and source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/12 15:08
S65 7	308	((crystalline or crystallize) near semiconductor adj film) same drain and source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/12 15:15
S65 8	7	((crystalline or crystallize) near semiconductor adj film) same drain and source and sram and bit adj line	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/12 15:09
S65 9	0	silicide with (semiconductor adj film) same drain and source and sram and bit adj line	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/12 15:10
S66 0	1	silicide same (semiconductor adj film) same drain and source and sram and bit adj line	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/12 15:10
S66 1	1	"5247198".PN.	USPAT; USOCR	OR	ON	2005/04/12 16:02

S66 2	1	"5061647".PN.	USPAT; USOCR	OR	ON	2005/04/12 16:08
S66 3	1	"4905073".PN.	USPAT; USOCR	OR	ON	2005/04/12 16:09